Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K16FU

High Speed Switching Applications Analog Switching Applications

• Suitable for high-density mounting due to compact package

• Low on resistance: $R_{on} = 3.0 \Omega$ (max) (@VGS = 4 V)

: $R_{on} = 4.0 \Omega \text{ (max) } (@V_{GS} = 2.5 \text{ V})$

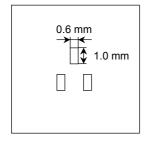
: $R_{on} = 15 \Omega (max) (@V_{GS} = 1.5 V)$

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DS}	20	V	
Gate-Source voltage		V_{GSS}	±10	V	
Drain current	DC	I _D	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25°C)		P _D (Note)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

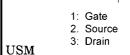
Note: Mounted on FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 0.6 \text{ mm}^2 \times 3)$



50 ± 0.2 10 ± 0

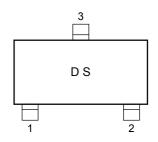
 2.1 ± 0.1

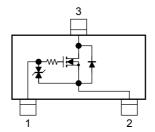


JEDEC	_		
JEITA	SC-70		
TOSHIBA	2-2E1E		

Marking

Equivalent Circuit





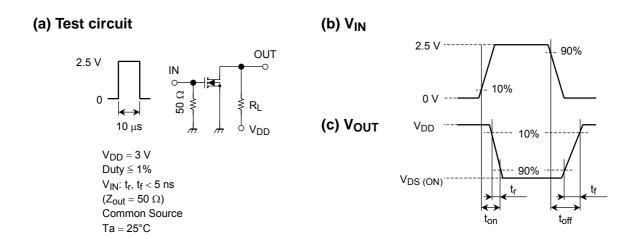
Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±1	μΑ
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	20	_	_	V
Drain cut-off current		I _{DSS}	V _{DS} = 20 V, V _{GS} = 0	_	_	1	μА
Gate threshold vo	Itage	V _{th}	V _{DS} = 3 V, I _D = 0.1 mA	0.6	_	1.1	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = 3 \text{ V}, I_D = 10 \text{ mA}$	40	_	_	mS
Drain-Source ON resistance		R _{DS} (ON)	I _D = 10 mA, V _{GS} = 4 V	_	1.5	3.0	Ω
			I _D = 10 mA, V _{GS} = 2.5 V	_	2.2	4.0	
			I _D = 1 mA, V _{GS} = 1.5 V	_	5.2	15	
Input capacitance		C _{iss}	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz	_	9.3	_	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz	_	4.5	_	pF
Output capacitance		Coss	$V_{DS} = 3 V$, $V_{GS} = 0$, $f = 1 MHz$	_	9.8	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0~2.5 \text{ V}$	_	70	_	ns
	Turn-off time	t _{off}			125		

Switching Time Test Circuit

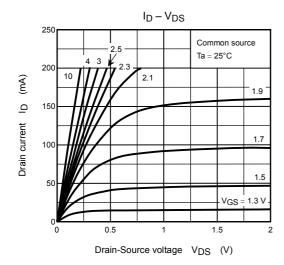


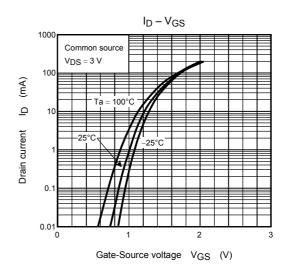
Precaution

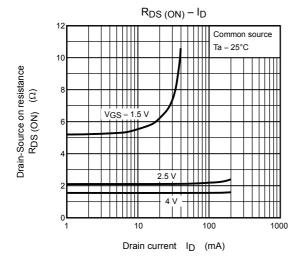
 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = 100 μA for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} . (Relationship can be established as follows: V_{GS} (off) < V_{th} < V_{GS} (on))

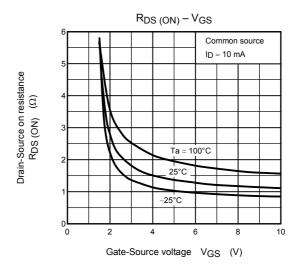
Please take this into consideration for using the device. $V_{\rm GS}$ recommended voltage of 1.5 V or higher to turn on this product.

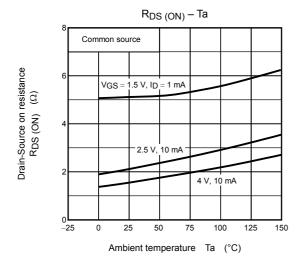
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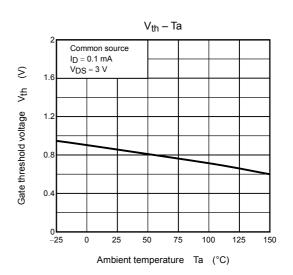




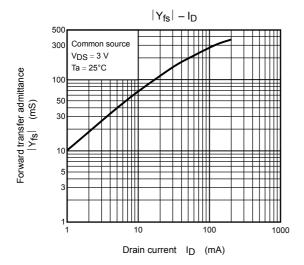


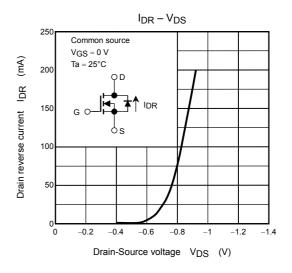


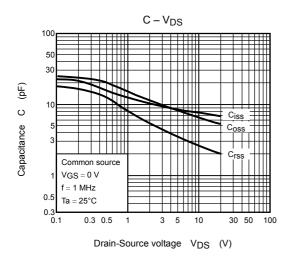


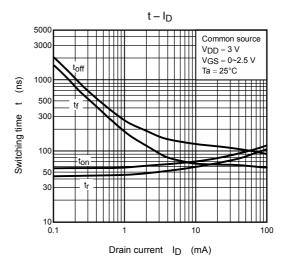


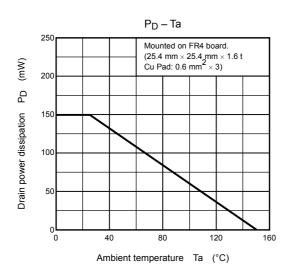
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RESTRICTIONS ON PRODUCT USE

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 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
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